NSN 5961-01-536-0034

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-536-0034 **Inclosure Material:** Plastic **Overall Length:** Between 0.039 inches and 0.055 inches **Terminal Length:** 0.016 inches **Overall Height:** Between 0.020 inches and 0.031 inches **Overall Width:** Between 0.028 inches and 0.035 inches **End Application:** F16A-IR-CRA-FT;N **Mounting Method: Terminal Terminal Circle Diameter:** 0.009 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 250.00 milliamperes source cutoff current preset and 250.00 milliamperes source cutoff current outside diameter and 1000.00 milliamperes forward current, average preset **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Terminal Type And Quantity:** 2 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: